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# The effective mass of a slow-moving surface polaron in a semi-infinite crystal

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**Abstract.** There is weak bulk but strong surface coupling between electrons and phonons in a semi-infinite crystal. Here some properties of the surface polaron in a semi-infinite crystal, weak coupling with bulk longitudinal optical (BO) phonons and strong coupling with surface longitudinal optical (SO) phonons, are studied. The effective Hamiltonian of a slow-moving surface polaron in a semi-infinite crystal is derived using an improved linear combination operator and perturbation method. If we consider the interaction between phonons of different wave vectors in the recoil process, the influence of this interaction on the effective Hamiltonian, the induced potential and the effective mass of the surface polaron are discussed. Numerical calculations for an AgBr crystal, as an example, are performed, and some properties of the surface polaron in a semi-infinite crystal are discussed.

## 1. Introduction

In the early 1970s, Ibach [1] carried out low-energy electron diffraction (LEED) experiments on ZnO and other semiconductor surfaces. The surface or interface polarons in the crystals are of considerable interest. The behaviour of the electron–phonon interaction near the surface or interface of a crystal has been studied by many investigators [2–4]. Evans and Mills [5], using a variational approach, investigated the case where the electron interacted with both surface and bulk LO waves and the phonons were considered as the only electric-dipole active excitations. Gu *et al* [6, 7] discussed the ideal surface polaron and the weak, intermediate-coupling polaron in a semi-infinite polar crystal by means of the perturbation method.

Huybrechts [8] proposed a linear combination operator method, by which a strong-coupling polaron was investigated. Later, other authors [9–11] studied many aspects of the strong-coupling polaron by this method. On the basis of Huybrechts' work, Tokuda [12] added another variational parameter to the momentum operator and also evaluated the ground-state energy and effective mass of the bulk polaron. In fact, so far research on the polaron has been restricted to approximation and calculation where the interaction between phonons of different wave vectors in the recoil process is neglected. The properties of

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the surface polaron, considering the corresponding interaction, have been discussed by the perturbation method by the present authors and co-workers [13].

For the bulk polaron, the weak- and intermediate-coupling theories are applicable for the electron–bulk longitudinal optical phonon coupling constant  $\alpha_l < 6$  [14], whereas for the surface polaron this confinement is about 2.5 [3]. Hence, when the electron–surface optical phonon coupling constant satisfies  $\alpha_s > 2.5$ , the strong-coupling theory must be applied. There is weak coupling between the electron and the bulk longitudinal optical phonon, but strong coupling between the electron and the surface optical phonon for many polar crystals. So far, research into this has been very scarce.

In this paper, the effect of the interaction between phonons of different wave vectors in the recoil process on the properties of the surface polaron in a semi-infinite crystal are studied by using an improved linear combination operator and perturbation method. With both the weak coupling between the electron and bulk LO phonon and the strong coupling between the electron and SO phonon included, we obtain an expression for the effective Hamiltonian of the surface polaron. If we consider the interaction between phonons of different wave vectors in the recoil process, the influence on the effective Hamiltonian, induced potential, effective interaction potential and effective mass of the surface polaron are investigated. Numerical calculations, taking the AgBr crystal example, are performed and the properties of these quantities for the surface polaron in a semi-infinite crystal are discussed.

## 2. Hamiltonian

A surface between an AgBr crystal and vacuum is perpendicular to the  $z$  axis; the semi-infinite space  $z > 0$  is occupied by the AgBr crystal, whereas the space  $z < 0$  is a vacuum. We consider a slow electron moving in an AgBr crystal which occupies the half space  $z > 0$ . Using the Hamiltonian of the interaction between an electron and SO phonons and bulk LO phonons that has been given by Evans and Mills [5], including the surface repulsive image potential with dielectric constant  $\varepsilon_\infty (\neq 1)$  from the polarization of the electron cloud, the Hamiltonian of the electron–phonon system in explicit form can be written as ( $\hbar = m = 1$ ;  $m$  is the band mass of the electron)

$$H = \frac{P_{\parallel}^2}{2} + \frac{P_z^2}{2} + \frac{e^2(\varepsilon_\infty - 1)}{4z\varepsilon_\infty(\varepsilon_\infty + 1)} + \sum_W \omega_l a_W^+ a_W + \sum_Q \omega_s b_Q^+ b_Q \\ + \sum_W \sin(w_z z) (V_W^* e^{-iW \cdot \rho} a_W^+ + \text{HC}) + \sum_Q e^{-QZ} (V_Q^* e^{-iQ \cdot \rho} b_Q^+ + \text{HC}) \quad (1a)$$

$$V_W^* = i \left( \frac{4\pi e^2 \omega_l}{\varepsilon V} \right)^{\frac{1}{2}} \frac{1}{W} \quad (1b)$$

$$V_Q^* = i \left( \frac{\pi e^2 \omega_s}{\varepsilon^* S} \right)^{\frac{1}{2}} \quad (1c)$$

$$\frac{1}{\varepsilon} = \frac{1}{\varepsilon_\infty} - \frac{1}{\varepsilon_0} \quad (1d)$$

$$\frac{1}{\varepsilon^*} = \frac{\varepsilon_0 - 1}{\varepsilon_0 + 1} = \frac{\varepsilon_\infty - 1}{\varepsilon_\infty + 1}. \quad (1e)$$

In (1a),  $a_{\mathbf{W}}^+$  ( $a_{\mathbf{W}}$ ) is the creation (annihilation) operator of a bulk LO phonon with three-dimensional wave vector  $\mathbf{W}$ ,  $b_{\mathbf{Q}}^+$  ( $b_{\mathbf{Q}}$ ) is the corresponding operator for the SO phonon with two-dimensional wave vector  $\mathbf{Q}$ .  $P_{\parallel}$  and  $\rho$  are the momentum and position vector, respectively, of an electron in a plane parallel to the surface.  $P_z$  and  $z$  are the momentum and position, respectively, of the electron in the  $z$  direction.  $\omega_l$  and  $\omega_s$  are the frequencies of the bulk LO and SO phonons.  $S$  and  $V$  are the surface area and the volume of the crystal.  $\varepsilon_0$  and  $\varepsilon_{\infty}$  are, respectively, the static and high-frequency dielectric constant of the crystal (in (1a) the subscript  $\parallel$  denotes the projection of a given vector onto a plane parallel to the surface).

The Hamiltonian can formally be divided into two parts:

$$H = H_z + H_{\parallel} \quad (2a)$$

where

$$H_z = \frac{P_z^2}{2} + \frac{e^2(\varepsilon_{\infty} - 1)}{4z\varepsilon_{\infty}(\varepsilon_{\infty} + 1)} \quad (2b)$$

and the rest is called  $H_{\parallel}$ . Assuming the motion in the  $z$  direction to be slow, in determining the motion state in the  $x$ - $y$  plane, the quantities such as the momentum and position in the  $z$  direction may be regarded as parameters. This procedure is exactly analogous to the quasi-adiabatic approximation [7, 15, 16]. We calculate  $H_{\parallel}$ , then add the calculated result to  $H_z$  so as to obtain the effective Hamiltonian of the system. For the motion parallel to the  $x$ - $y$  plane we introduce unitary transformations to the Hamiltonian  $H_{\parallel}$  with

$$U_1 = \exp\left(-i\left(\sum_{\mathbf{W}} A_1 a_{\mathbf{W}}^+ a_{\mathbf{W}} \mathbf{W}_{\parallel} + \sum_{\mathbf{Q}} A_2 b_{\mathbf{Q}}^+ b_{\mathbf{Q}} \mathbf{Q}\right) \cdot \rho\right) \quad (3a)$$

$$U_2 = \exp\left(\sum_{\mathbf{W}} (a_{\mathbf{W}}^+ f_{\mathbf{W}} - a_{\mathbf{W}} f_{\mathbf{W}}^*) + \sum_{\mathbf{Q}} (b_{\mathbf{Q}}^+ g_{\mathbf{Q}} - b_{\mathbf{Q}} g_{\mathbf{Q}}^*)\right) \quad (3b)$$

where  $f_{\mathbf{W}}$  ( $f_{\mathbf{W}}^*$ ) and  $g_{\mathbf{Q}}$  ( $g_{\mathbf{Q}}^*$ ) are variational parameters.  $A_i$  ( $i = 1, 2$ ) is a parameter characterizing the coupling strength. In the unitary transformation  $U_1$ ,  $A_i = 1$  corresponds to the weak-coupling limit and  $A_i = 0$  corresponds to the strong-coupling limit.

Following Tokuda [12] we also introduce the linear combination of the creation operator  $b_j^+$  and annihilation operator  $b_j$  to represent the momentum and position of the electron:

$$P_{\parallel j} = \left(\frac{\lambda}{2}\right)^{\frac{1}{2}} (b_j + b_j^+ + P_{0j}) \quad (4a)$$

$$\rho_j = i \left(\frac{1}{2\lambda}\right)^{\frac{1}{2}} (b_j - b_j^+) \quad (4b)$$

where the subscript  $j$  refers to the  $x$  and  $y$  directions,  $\lambda$  and  $P_0$  are the variational parameters, and  $b_j^+$  and  $b_j$  are Boson operators satisfying the Boson commutative relation. Applying the transformations (3a) and (3b) to the Hamiltonian  $H_{\parallel}$  and using the operator expressions (4a) and (4b) and the fact that, in the unitary transformation  $U_1$ ,  $A_1 = 1$  corresponds to the weak coupling between the electron and the bulk LO phonon and  $A_2 = 0$  corresponds to the strong coupling between the electron and SO phonon, we can easily obtain

$$\mathcal{H}_{\parallel} = U_2^{-1} U_1^{-1} H_{\parallel} U_1 U_2 = \mathcal{H}_{\parallel}^0 + \mathcal{H}'_{\parallel} \quad (5a)$$

$$\begin{aligned} \mathcal{H}_{\parallel}^0 = & \frac{\lambda}{2} \left( \sum_j b_j^+ b_j + 1 \right) + \frac{\lambda}{4} \sum_j (b_j^+ b_j^+ + b_j b_j + P_{0j}^2) + \frac{\lambda}{2} \sum_j (b_j^+ + b_j) P_{0j} \\ & + \sum_{\mathbf{W}} \omega_l (a_{\mathbf{W}}^+ + f_{\mathbf{W}}^*) (a_{\mathbf{W}} + f_{\mathbf{W}}) + \sum_{\mathbf{Q}} \omega_s (b_{\mathbf{Q}}^+ + g_{\mathbf{Q}}^*) (b_{\mathbf{Q}} + g_{\mathbf{Q}}) \\ & + \frac{1}{2} \left( \sum_{\mathbf{W}} \mathbf{W}_{\parallel} (a_{\mathbf{W}}^+ + f_{\mathbf{W}}^*) (a_{\mathbf{W}} + f_{\mathbf{W}}) \right)^2 - \left( \frac{\lambda}{2} \right)^{\frac{1}{2}} \sum_{\mathbf{W}} (a_{\mathbf{W}}^+ + f_{\mathbf{W}}^*) (a_{\mathbf{W}} + f_{\mathbf{W}}) \\ & \times \sum_j (b_j^+ + b_j + P_{0j}) + \sum_{\mathbf{W}} \sin(W_z z) (V_{\mathbf{W}}^* (a_{\mathbf{W}}^+ + f_{\mathbf{W}}^*) + \text{HC}) \\ & + \sum_{\mathbf{Q}} e^{-Qz} (V_{\mathbf{Q}}^* (b_{\mathbf{Q}}^+ + g_{\mathbf{Q}}^*) + \text{HC}) e^{-(Q^2/4\lambda)} \\ & \times e^{-(1/2\lambda)^{\frac{1}{2}} \sum_j b_j^+ Q_j} e^{(1/2\lambda)^{\frac{1}{2}} \sum_j b_j Q_j} + \text{HC} \end{aligned} \quad (5b)$$

$$\mathcal{H}'_{\parallel} = \frac{1}{2} \sum_{\mathbf{W} \neq \mathbf{W}'} \mathbf{W}_{\parallel} \cdot \mathbf{W}'_{\parallel} (a_{\mathbf{W}}^+ + f_{\mathbf{W}}^*) (a_{\mathbf{W}} + f_{\mathbf{W}}) (a_{\mathbf{W}'}^+ + f_{\mathbf{W}'}) (a_{\mathbf{W}'} + f_{\mathbf{W}'}) \quad (5c)$$

(5c) is the term describing the interaction between phonons of different wave vectors in the recoil process. The ground-state wavefunction of the system is  $\phi = \varphi(\rho)|0\rangle$  where  $\varphi(\rho)$  is the normalized surface polaron wavefunction.  $|0\rangle$  is the zero-phonon state, which satisfies

$$a_{\mathbf{W}}|0\rangle = b_{\mathbf{Q}}|0\rangle = b_j|0\rangle = 0. \quad (6)$$

In the variation for minimizing the ground-state energy with respect to the variational parameter and the functions mentioned above, the system must be constrained by the conservation of total momentum. However, in the quasi-adiabatic approximation, the momentum in the  $z$  direction is regarded as a parameter; so it is only constrained by the total momentum parallel to the  $x$ - $y$  plane;

$$\mathbf{P}_{\parallel T} = \mathbf{P}_{\parallel} + \sum_{\mathbf{W}} \mathbf{W}_{\parallel}^+ a_{\mathbf{W}}^+ a_{\mathbf{W}} + \sum_{\mathbf{Q}} \mathbf{Q} b_{\mathbf{Q}}^+ b_{\mathbf{Q}}. \quad (7)$$

The minimization problem is now carried out by the use of the Lagrange multiplier  $\mathbf{u}$ ; we have

$$\langle \phi | \mathbf{H}_{\parallel}^0 - U_2^{-1} U_1^{-1} \mathbf{u} \cdot \mathbf{P}_{\parallel T} U_1 U_2 | \phi \rangle = \langle \varphi(\rho) | F(\lambda, f_{\mathbf{W}}, g_{\mathbf{Q}}, \mathbf{u}, p_0) | \varphi(\rho) \rangle \quad (8a)$$

where

$$\begin{aligned} F(\lambda, f_{\mathbf{W}}, g_{\mathbf{Q}}, \mathbf{u}, p_0) = & \langle 0 | \mathcal{H}_{\parallel}^0 - U_2^{-1} U_1^{-1} \mathbf{u} \cdot \mathbf{P}_{\parallel T} U_1 U_2 | 0 \rangle = \frac{\lambda}{2} + \frac{\lambda}{4} p_0^2 + \sum_{\mathbf{W}} \omega_l |f_{\mathbf{W}}|^2 \\ & + \sum_{\mathbf{Q}} \omega_s |g_{\mathbf{Q}}|^2 + \frac{1}{2} \left( \sum_{\mathbf{W}} |f_{\mathbf{W}}|^2 \mathbf{W}_{\parallel} \right)^2 + \frac{1}{2} \sum_{\mathbf{W}} |f_{\mathbf{W}}|^2 \mathbf{W}_{\parallel}^2 \\ & - \left( \frac{\lambda}{2} \right)^{\frac{1}{2}} \sum_{\mathbf{W}} |f_{\mathbf{W}}|^2 \mathbf{p}_0 \cdot \mathbf{W}_{\parallel} + \sum_{\mathbf{W}} \sin(w_z z) (V_{\mathbf{W}}^* f_{\mathbf{W}}^* + V_{\mathbf{W}} f_{\mathbf{W}}) \\ & + \sum_{\mathbf{Q}} e^{-Qz} (V_{\mathbf{Q}}^* g_{\mathbf{Q}}^* + V_{\mathbf{Q}} g_{\mathbf{Q}}) e^{-(Q^2/4\lambda)} - \left( \frac{\lambda}{2} \right)^{\frac{1}{2}} \mathbf{p}_0 \cdot \mathbf{u} - \sum_{\mathbf{Q}} \mathbf{Q} \cdot \mathbf{u} |g_{\mathbf{Q}}|^2 \end{aligned} \quad (8b)$$

$F(\lambda, f_W, g_Q, u, p_0)$  may be called the variational parameter function. Minimizing (8b) with respect to  $\lambda, f_W, g_Q, u$  and  $p_0$ , we can determine these parameters and functions. Using the variational method, we obtain

$$f_W = -\frac{V_W^* \sin(W_z z)}{\omega_l + W_{\parallel}^2/2 - ((\lambda/2)^{1/2} - \eta) \mathbf{p}_0 \cdot \mathbf{W}_{\parallel}} \quad (9a)$$

$$g_Q = -\frac{e^{-Qz} V_Q^* e^{-(Q^2/4\lambda)}}{\omega_s \mathbf{Q} \cdot \mathbf{u}}. \quad (9b)$$

According to the Lee–Low–Pines [17] variation technique, if it is noted that the only preferred direction in the  $x$ - $y$  plane is that of  $\mathbf{p}_0$ , we may conveniently introduce the parameter defined by

$$\sum_W |f_W|^2 \mathbf{W}_{\parallel} = \eta \mathbf{p}_0. \quad (10)$$

Substituting (9a) into (10), we obtain

$$\eta = \frac{2\alpha_l f_1(z)}{1 + 2\alpha_l f_1(z)} \left(\frac{\lambda}{2}\right)^{\frac{1}{2}} \quad (11a)$$

$$f_1(z) = \frac{\pi}{8} - 2 \int_0^{\infty} \frac{x^2 e^{-2u_l z x}}{(1+x^2)^3} dx. \quad (11b)$$

Substituting (9) into (8b), the final two terms in (8b) can be calculated by replacing the summation with integration and expanding them up to the second-order term of  $u$  and  $p_0$  for a slow electron. In this expression, the first-order terms in  $\mathbf{p}_0 \cdot \mathbf{W}_{\parallel}$  and  $\mathbf{Q} \cdot \mathbf{u}$  are equal to zero; thus, we have

$$\begin{aligned} F(\lambda, u, p_0) &= \frac{\lambda}{2} + \frac{\lambda}{4} p_0^2 - \left(\frac{\lambda}{2}\right)^{\frac{1}{2}} \mathbf{p}_0 \cdot \mathbf{u} - \alpha_l \omega_l f_2(z) - \alpha_l p_0^2 \left( \lambda - 3 \left(\frac{\lambda}{2}\right)^{\frac{1}{2}} \eta + \eta^2 \right) f_1(z) \\ &+ \frac{\alpha_l^2 p_0^2}{2} \left( \left(\frac{\lambda}{2}\right)^{\frac{1}{2}} - \eta \right)^2 f_1^2(z) - \alpha_s \omega_s \left(\frac{\lambda}{\omega_s}\right)^{\frac{1}{2}} \int_0^{\infty} e^{-x^2 - 2u_s z x} dx \\ &- \alpha_s u^2 \left(\frac{\lambda}{\omega_s}\right)^{\frac{3}{2}} \int_0^{\infty} x^2 e^{-x^2 - 2u_s z x} dx \end{aligned} \quad (12a)$$

where

$$f_2(z) = \frac{\pi}{2} - \int_0^{\infty} \frac{e^{2u_l z x}}{1+x^2} dx \quad (12b)$$

$$\alpha_l = \frac{e^2}{\varepsilon u_l} \quad \alpha_s = \frac{e^2}{\varepsilon^* u_s} \quad (12c)$$

$$u_l = (2\omega_l)^{\frac{1}{2}} \quad u_s = (2\omega_s)^{\frac{1}{2}} \quad u_{\lambda} = (2\lambda)^{\frac{1}{2}}. \quad (12d)$$

The extremum condition  $\partial F/\partial p_0 = 0$  given by

$$\mathbf{p}_0 = \left(\frac{2}{\lambda}\right)^{\frac{1}{2}} \frac{(1 + 2\alpha_l f_1(z))^2}{1 + 3\alpha_l f_1(z) + \alpha_l^2 f_1^2(z)} \mathbf{u} \quad (13a)$$

$$\langle 0 | \mathbf{u} \cdot \mathbf{p}_0 | 0 \rangle = 2\alpha_s u^2 \left(\frac{\lambda}{\omega_s}\right)^{\frac{3}{2}} \int_0^{\infty} x^2 e^{-x^2 - 2u_s z x} dx + u^2 \left\{ \frac{(1 + 2\alpha_l f_1(z))^2}{1 + 3\alpha_l f_1(z) + \alpha_l^2 f_1^2(z)} \right\}. \quad (13b)$$

Finally, the Hamiltonian of the surface polaron in a plane parallel to the surface, which omits the interaction between phonons of different wave vectors in the recoil process, can be expressed as

$$\mathcal{H}_{\parallel}^0 = F(\lambda, u) - \langle 0 | \mathbf{u} \cdot \mathbf{p}_0 | 0 \rangle = \frac{\lambda}{2} + \frac{p_{\parallel}^2}{2m^*} - \alpha_l \omega_l f_2(z) + \alpha_s \omega_s \left( \frac{\lambda}{\omega_s} \right)^{\frac{1}{2}} \int_0^{\infty} e^{-x^2 - 2u_{\lambda} z x} dx \quad (14a)$$

where

$$m^* = \frac{(1 + 2\alpha_l f_1(z))^2}{1 + 3\alpha_l f_1(z) + \alpha_l^2 f_1^2(z)} + 2\alpha_s \left( \frac{\lambda}{\omega_s} \right)^{\frac{3}{2}} \int_0^{\infty} x^2 e^{-x^2 - 2u_{\lambda} z x} dx \quad (14b)$$

is the effective mass of the surface polaron, which omits the corresponding interaction. Performing the variation of  $\mathcal{H}_{\parallel}^0$  with respect to  $\lambda$ , we obtain

$$\lambda^{1/2} = \alpha_s \sqrt{\omega_s} \int_0^{\infty} (1 - 2u_{\lambda} z x) e^{-x^2 - 2u_{\lambda} z x} dx. \quad (15)$$

### 3. Perturbation calculation

We regard  $\mathcal{H}_{\parallel}^0$  as the unperturbed Hamiltonian of the surface polaron–phonon system, and  $\mathcal{H}'_{\parallel}$  as the perturbation part in the perturbation calculation. The first-order perturbation energy induced by  $\mathcal{H}'_{\parallel}$  is zero. Now we are ready to calculate the second-order perturbation energy,

$$\Delta E' = - \sum_n \frac{|\langle \mathcal{H}'_{\parallel} \rangle_{0n}|^2}{E_n - E_0} = -\alpha_l^2 \omega_l f_3(z) - \frac{u^2 (1 + 2\alpha_l f_1(z))^2 \alpha_l^2}{2(1 + 3\alpha_l f_1(z) + \alpha_l^2 f_1^2(z))^2} (3f_4(z) + f_5(z)) \quad (16a)$$

$$f_3(z) = \frac{1}{2} \int_0^{\infty} \int_0^{\infty} \frac{x^2 y^2 (1 - e^{-2u_{\lambda} z x})(1 - e^{-2u_{\lambda} z y})}{(1 + x^2)^2 (1 + y^2)^2 (2 + x^2 + y^2)} dx dy \quad (16b)$$

$$f_4(z) = \int_0^{\infty} \int_0^{\infty} \frac{x^4 y^2 (1 - e^{-2u_{\lambda} z x})(1 - e^{-2u_{\lambda} z y})}{(1 + x^2)^4 (1 + y^2)^2 (2 + x^2 + y^2)} dx dy \quad (16c)$$

$$f_5(z) = \int_0^{\infty} \int_0^{\infty} \frac{x^4 y^2 (1 - e^{-2u_{\lambda} z x})(1 - e^{-2u_{\lambda} z y})}{(1 + x^2)^2 (1 + y^2)^2 (1 + x^2 + y^2)^3} dx dy. \quad (16d)$$

In (16a), the first term, being proportional to the squared coupling constant  $\alpha_l^2$ , is the extra energy of the induced potential of the surface polaron, considering interaction between phonons of different wave vectors in the recoil process. The second term, being proportional to the squared coupling constant  $\alpha_l^2$ , is the extra effective mass of the surface polaron, considering the corresponding interaction. Finally, the effective Hamiltonian of the surface polaron can be expressed as

$$\mathcal{H}_{eff} = H_z + \mathcal{H}_{\parallel}^0 + \Delta E' = \frac{P_z^2}{2} + \frac{P_{\parallel}^2}{2m^*} + \frac{\lambda}{2} + V_{img} + V_i^b + V_i^s \quad (17a)$$

where

$$V_{img} = \frac{e^2(\varepsilon_\infty - 1)}{4z\varepsilon_\infty(\varepsilon_\infty - 1)} \quad (17b)$$

$$V_i^b = -\alpha_l \omega_l f_2(z) - \alpha_l^2 \omega_l f_3(z) \quad (17c)$$

$$V_i^s = \alpha_s \omega_s \left( \frac{\lambda}{\omega_s} \right)^{\frac{1}{2}} \int_0^\infty e^{-x^2 - 2u_s z x} dx \quad (17d)$$

$$m^* = \frac{(1 + 2\alpha_l f_1(z))^2}{1 + 3\alpha_l f_1(z) + \alpha_l^2 f_1^2(z)} \left( 1 - \frac{\alpha_l^2 (3f_4(z) + f_5(z))}{1 + 3\alpha_l f_1(z) + \alpha_l^2 f_1^2(z)} \right) + 2\alpha_s \left( \frac{\lambda}{\omega_s} \right)^{\frac{3}{2}} \int_0^\infty x^2 e^{-x^2 - 2u_s z x} dx \quad (17e)$$

are the image potential, the potential induced by the electron–LO phonon interaction, the potential induced by the electron–SO phonon interaction and the effective mass of the surface polaron, respectively. The effective interaction potential of the surface polaron is defined as

$$V_{eff} = V_{img} + V_i^b + V_i^s. \quad (17f)$$

Evidently, the induced potential  $V_i^b$ , the effective mass  $m^*$  and the effective interaction potential  $V_{eff}$  of the surface polaron depend on the interaction between phonons of different wave vectors in the recoil process.

#### 4. Results and discussion

To show more obviously the influence of the interaction between phonons of different wave vectors in the recoil process on the properties of the surface polaron, taking the polaron in the surface of an AgBr crystal as an example, we perform a numerical evaluation. In table 1, the data for an AgBr crystal are given.

**Table 1.** The data for an AgBr crystal. All the parameters are taken from [18].

Material	$\varepsilon_0$	$\varepsilon_\infty$	$\hbar\omega_l$ (meV)	$\hbar\omega_s$ (meV)	$\alpha_l$	$\alpha_s$	$u_l$ (cm <sup>-1</sup> )	$u_s$ (cm <sup>-1</sup> )
AgBr	10.6	4.68	17.1	14.5	1.56	2.56	$311.5 \times 10^4$	$286.8 \times 10^4$

Figure 1 shows the relationships between the image potential  $V_{img}$ , the induced potential  $V_i^b$  resulting from the electron–bulk LO phonon interaction, the induced potential  $V_i^s$  resulting from the electron–SO phonon interaction, and the effective interaction potential  $V_{eff}$  of the surface polaron in the AgBr crystal, considering the corresponding interactions, and the coordinate  $z$ . From figure 1 one can see that the induced potential  $V_i^s$  of the surface polaron will decrease with increasing coordinate  $z$ , whereas the induced potential  $V_i^b$  of the surface polaron will increase with increasing coordinate  $z$ . Near the surface the electron–SO phonon interaction is dominant, whereas in the bulk far from the surface the electron–bulk LO phonon interaction is dominant. As  $z \rightarrow 0$ , the first term of (17f) is dominant, and the surface polaron will be repulsed away from the surface. Thus the surface polaron cannot approach infinitely close to the surface; there is no surface polaron in the range near the

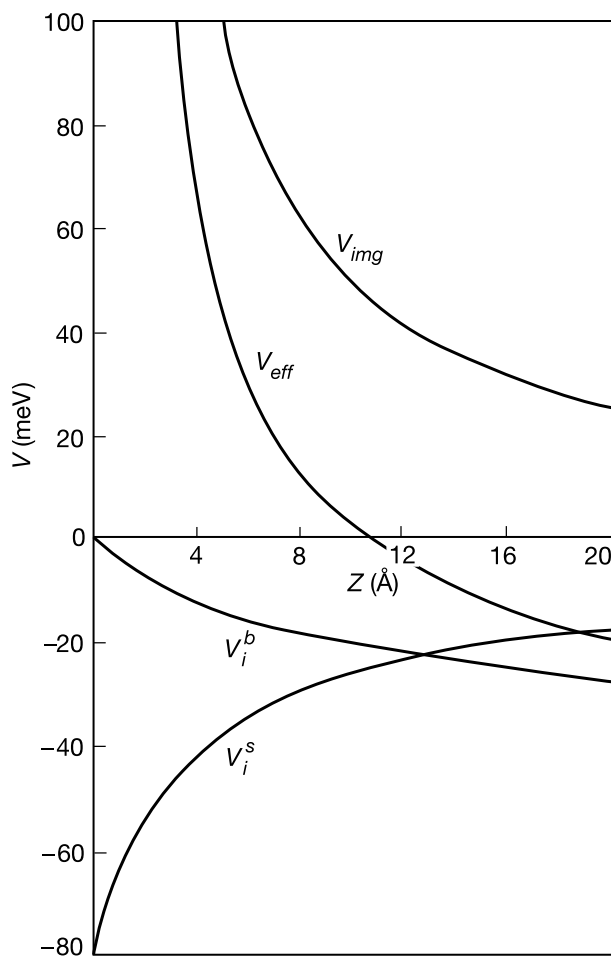


surface ( $V_{eff} > 0$ ). Because of the similarity to the case of excitons we call the thin layer the surface-polaron-free surface layer (SPFSL) or the dead layer of surface polarons. Solving the equation

$$V_{eff}(z) = 0 \quad (18)$$

the root is the depth of the SPFSL, which we denote as  $d$  (for the AgBr crystal,  $d = 10.67 \text{ \AA}$ ).

This shows that, when the distance between the electron and the surface is much smaller than the radius of the bulk polaron the effect of the bulk phonons can be neglected, and so can the effect of the surface phonons when the corresponding distance is much larger than the corresponding radius.



**Figure 1.** The relational curves of  $V_{img}$ ,  $V_i^s$ ,  $V_i^b$  and  $V_{eff}$  with coordinate  $z$ .

In general, as the distance between the electron and the surface is of the same order of magnitude as the radius of the bulk polaron, the effects of both the bulk LO and the SO phonons must be taken into account. In this case the electron moves in a non-local potential as given by (17a) [7].

The effective mass  $m^*$  of the surface polaron can be expressed as

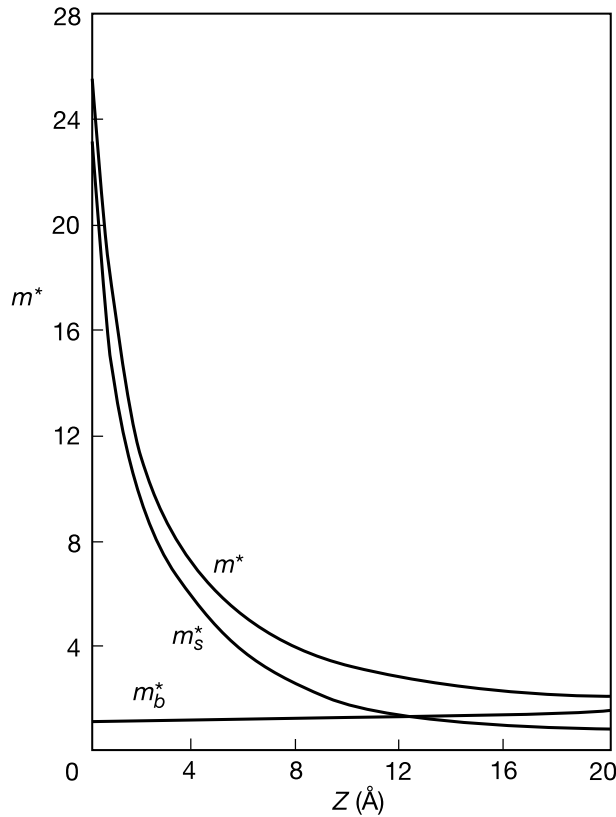
$$m^* = m_b^* + m_s^* \quad (19a)$$

where

$$m_b^* = \frac{(1 + 2\alpha_l f_1(z))^2}{1 + 3\alpha_l f_1(z) + \alpha_l^2 f_1^2(z)} - \frac{\alpha_l^2 (1 + 2\alpha_l f_1(z))^2 (3f_4(z) + f_5(z))}{(1 + 3\alpha_l f_1(z) + \alpha_l^2 f_1^2(z))^2} \quad (19b)$$

$$m_s^* = 2\alpha_s \left( \frac{\lambda}{\omega_s} \right)^{\frac{3}{2}} \int_0^\infty x^2 e^{-x^2 - 2u_l z x} dx \quad (19c)$$

are the effective mass induced by the electron–bulk LO phonon interaction and by the electron–SO phonon interaction, respectively. Figure 2 gives the relationship between the effective masses of the surface polaron  $m^*$ ,  $m_b^*$  and  $m_s^*$  in an AgBr crystal with the coordinate  $z$ . From the figure one can see that the effective mass  $m_b^*$  induced by the electron–bulk LO phonon interaction will increase little with increasing coordinate  $z$ , whereas the effective mass  $m_s^*$  induced by the electron–SO phonon interaction and the effective mass  $m^*$  of the surface polaron will increase strongly with decreasing coordinate  $z$ .



**Figure 2.** The relational curve of  $m^*$  with coordinate  $z$  in the AgBr crystal.

Since there is weak bulk but strong surface coupling between electrons and phonons in polar crystals, the interaction between phonons of different wave vectors in the recoil process influences only the induced potential  $V_i^b$  and the effective mass  $m_b^*$  resulting from

the electron–bulk LO phonon interaction. The extra induced potential, considering the interaction between phonons of different wave vectors in the recoil process, is given by

$$V_{i2}^b = \alpha_l^2 \omega_l f_3(z). \quad (20a)$$

The induced potential, omitting the corresponding interaction, is

$$V_{i1}^b = \alpha_l^2 \omega_l f_2(z). \quad (20b)$$

The ratio of  $V_{i2}^b$  and  $V_{i1}^b$  is

$$\Delta_1 = \frac{V_{i2}^b}{V_{i1}^b} = \alpha_l \frac{f_3(z)}{f_2(z)}. \quad (20c)$$

The extra effective mass, considering the corresponding interaction, is given by

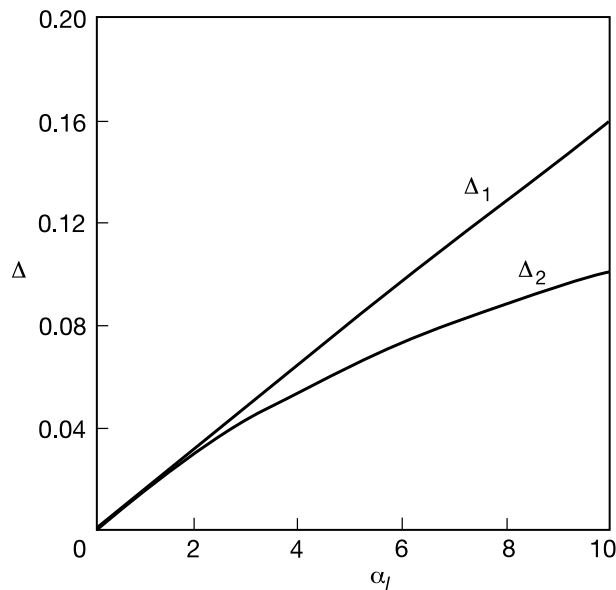
$$m_{b2}^* = \frac{\alpha_l^2 (1 + 2\alpha_l f_1(z))^2 (3f_4(z) + f_5(z))}{(1 + 3\alpha_l f_1(z) + \alpha_l^2 f_1^2(z))^2}. \quad (21a)$$

The effective mass, omitting the corresponding interaction, is

$$m_{b1}^* = \frac{(1 + 2\alpha_l f_1(z))^2}{1 + 3\alpha_l f_1(z) + \alpha_l^2 f_1^2(z)}. \quad (21b)$$

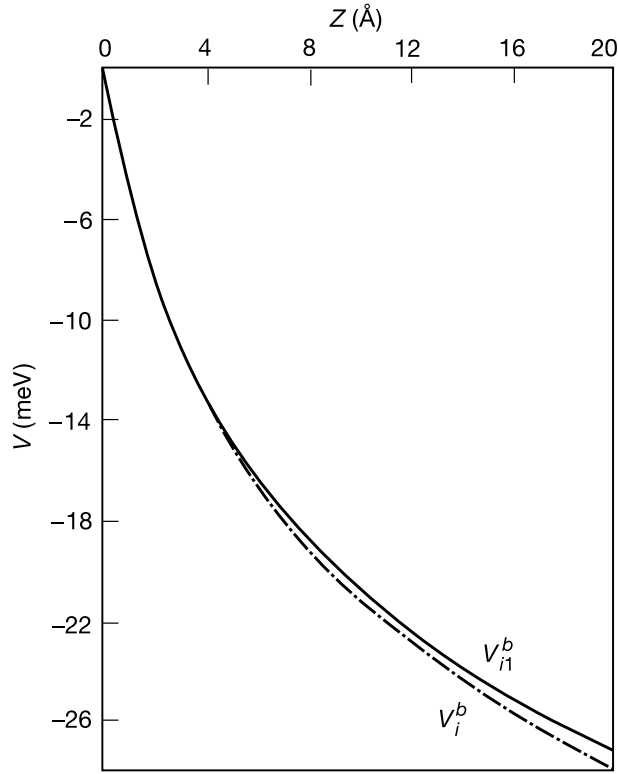
The ratio of  $m_{b2}^*$  and  $m_{b1}^*$  is

$$\Delta_2 = \frac{m_{b2}^*}{m_{b1}^*} = \frac{\alpha_l^2 (3f_4(z) + f_5(z))}{(1 + 3\alpha_l f_1(z) + \alpha_l^2 f_1^2(z))^2}. \quad (21c)$$



**Figure 3.** The relational curve of  $\Delta_1$  and  $\Delta_2$  with coupling constant  $\alpha_l$ .

Figure 3 gives a description of the variation of  $\Delta_1$  and  $\Delta_2$  with coupling constant  $\alpha_l$ :  $\Delta_1$  and  $\Delta_2$  increase with increasing coupling constant  $\alpha_l$ . For example, when  $\alpha_l = 3$  and 6, the ratio of the extra induced potential, considering the corresponding interaction, to the induced potential, omitting the corresponding interaction, is  $\Delta_1 = 4.8\%$  and  $9.6\%$ ; the



**Figure 4.** The relational curve of  $V_{i1}^b$  and  $V_i^b$  with coordinate  $z$  for the AgBr crystal.

ratio of the extra effective mass, considering the corresponding interaction, and the effective mass, omitting the corresponding interaction, is  $\Delta_2 = 4.2\%$  and  $7.2\%$ .

Figure 4 shows the relationship between the induced potential  $V_{i1}^b$ , omitting the corresponding interaction, and the induced potential  $V_i^b$ , considering the corresponding interaction, and the coordinate  $z$ . The solid curve denotes the case of  $V_{i1}^b$ ; the dashed one represents the case of  $V_i^b$ . From the figure, one can see that the induced potential  $V_{i1}^b$  and  $V_i^b$  will increase with increasing coordinate  $z$ ; moreover,  $V_i^b$  will increase more than  $V_{i1}^b$  with increasing coordinate  $z$ . Figure 5 shows the variation of the effective mass  $m_b^*$ , considering the corresponding interaction, and the effective mass  $m_{b1}^*$ , omitting the corresponding interaction, with the coordinate  $z$ . The solid curve denotes the case of  $m_{b1}^*$ ; the dashed one represents the case of  $m_b^*$ . It can be seen from figure 5 that the effective masses  $m_{b1}^*$  and  $m_b^*$  will decrease with increasing coordinate  $z$ ; moreover,  $m_b^*$  will decrease more than  $m_{b1}^*$  with increasing coordinate  $z$ .

## 5. Conclusion

Taking into account the interaction of an electron with both the weak-coupling bulk LO and the strong-coupling SO phonons we use an improved linear combination operator and perturbation methods to study the influence of the interaction between phonons of different wave vectors in the recoil process on the properties of the surface polaron in a semi-infinite

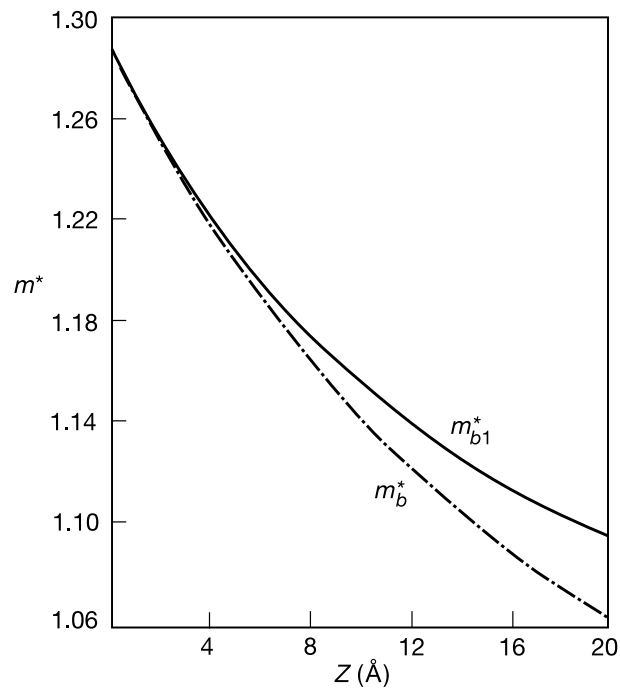


Figure 5. The relational curve of  $m_{b1}^*$  and  $m_b^*$  to coordinate  $z$  for the AgBr crystal.

crystal. Numerical calculations, taking the AgBr crystal as an example, are performed. The results show that the influence of the corresponding interaction on the induced potential and effective mass will increase with increasing coupling constant  $\alpha_l$ , and the influence on the induced potential will increase more with increasing coordinate  $z$ , and the influence on the effective mass will decrease more with increasing  $z$ .

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### References

- [1] Ibach H 1970 *Phys. Rev. Lett.* **24** 141  
Ibach H 1971 *Phys. Rev. Lett.* **27** 253
- [2] Lucas A A, Kartheuser E and Badro R G 1970 *Phys. Rev. B* **2** 2485
- [3] Pan J S 1985 *Phys. Status Solidi b* **127** 307  
Pan J S 1985 *Phys. Status Solidi b* **128** 287
- [4] Xiao J L, Sun B Q and Xiao W 1993 *Phys. Status Solidi b* **176** 117
- [5] Evans E and Mills L 1972 *Solid State Commun.* **11** 1093  
Evans E and Mills L 1973 *Phys. Rev. B* **8** 4004
- [6] Gu S W and Yan G 1982 *J. Semicond.* **3** 426 (in Chinese)
- [7] Liang X X and Gu S W 1984 *Solid State Commun.* **50** 505

- [8] Huybrechts J 1976 *J. Phys. C: Solid State Phys.* **9** L211
- [9] Gu S W and Zheng J 1984 *Phys. Status Solidi b* **121** K165
- [10] Tokuda N 1980 *J. Phys. C: Solid State Phys.* **13** L173
- [11] Sun B Q, Xiao W and Xiao J L 1994 *J. Phys.: Condens. Matter* **6** 8167
- [12] Tokuda N 1980 *J. Phys. C: Solid State Phys.* **13** L851
- [13] Xiao J L, Xing T H, Sun B Q and Xiao W 1994 *Phys. Status Solidi b* **183** 425
- [14] Haga E 1954 *Prog. Theor. Phys.* **11** 449
- [15] Wei B H and Gu S W 1991 *Phys. Rev. B* **43** 9190
- [16] Wei B H, Liu Y Y, Gu S W and Yu W K 1992 *Phys. Rev. B* **46** 4269
- [17] Lee T D, Low F E and Pines D 1953 *Phys. Rev.* **90** 297
- [18] Kartheuser E 1972 *Polarons in Ionic Crystals and Polar Semiconductors* (Amsterdam: North-Holland)